

Description

The AO3400H uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

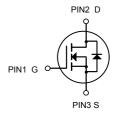


SOT-23

General Features

 $V_{DS} = 30V I_{D} = 5.7A$

 $R_{DS(ON)}$ < 28m Ω @ V_{GS}=10V



Application

Battery protection N-Channel MOSFET

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AO3400H	SOT-23	A09T	3000

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
VDS	Drain-Source Voltage	30	V
Vgs	Gate-Source Voltage	±12	V
I _D	Drain Current-Continuous	5.7	А
I DM	Drain Current-Pulsed (Note 1)	30	Α
P _D	Maximum Power Dissipation	1.4	W
TJ,Tstg	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$ C
RөJA	Thermal Resistance,Junction-to-Ambient (Note 2)	90	СW



Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	33	-	V
Zero Gate Voltage Drain Current	Inss	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	V_{DS} = V_{GS} , I_D =250 μA	0.7	0.9	1.4	V
	Rds(on)	V _{GS} =2.5V, I _D =4A	-	36	45	mΩ
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =5A	-	28	34	mΩ
		V _{GS} =10V, I _D =5.8A	-	24	28	mΩ
Forward Transconductance	grs	V _{DS} =5V,I _D =5A	10	-	-	S
Input Capacitance	C _{lss}		-	800	-	PF
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V,	-	100	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	78	-	PF
Turn-on Delay Time	td(on)		-	3.3	-	nS
Turn-on Rise Time	t _r	V_{DD} =15V, R_L =2.7 Ω	-	4.8	-	nS
Turn-Off Delay Time	td(off)	V_{GS} =10 V , R_{GEN} =3 Ω	-	26	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Qgs	V _{DS} =15V,I _D =5.8A,	-	1.6	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =4.5V	-	3.1	-	nC
Diode Forward Voltage (Note 3)	Vsp	V _{GS} =0V,I _S =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.8	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

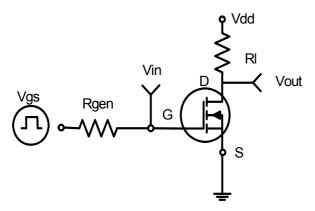


Figure 1:Switching Test Circuit

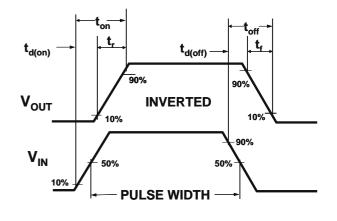


Figure 2:Switching Waveforms

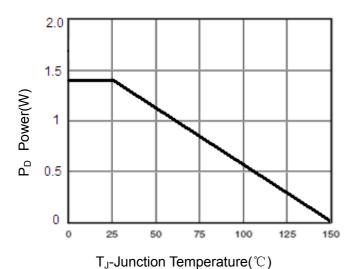


Figure 3 Power Dissipation

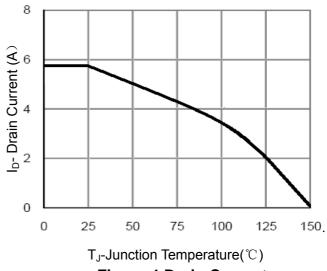


Figure 4 Drain Current

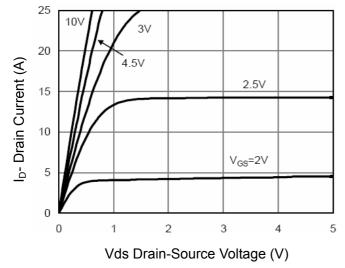


Figure 5 Output Characteristics

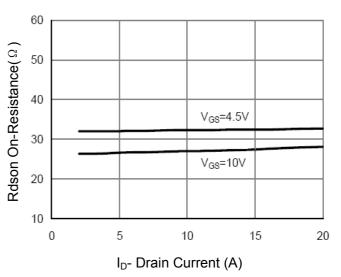


Figure 6 Drain-Source On-Resistance

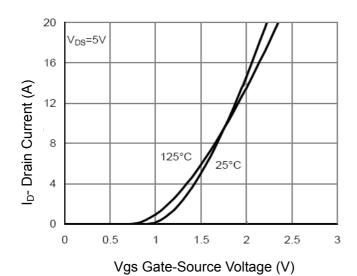


Figure 7 Transfer Characteristics

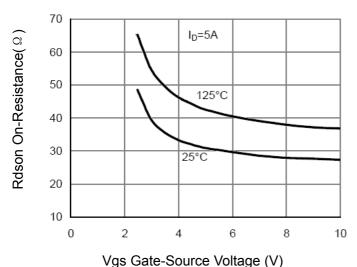


Figure 9 Rdson vs Vgs

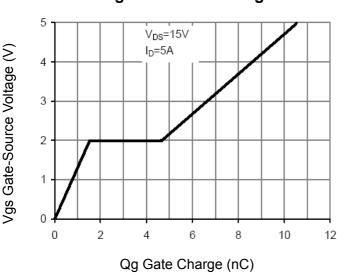


Figure 11 Gate Charge

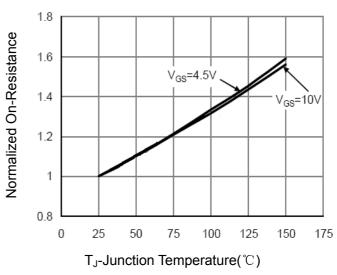


Figure 8 Drain-Source On-Resistance

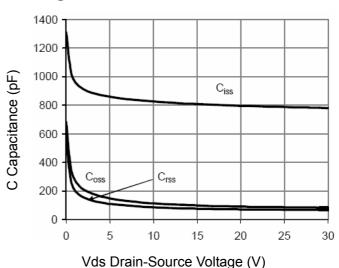


Figure 10 Capacitance vs Vds

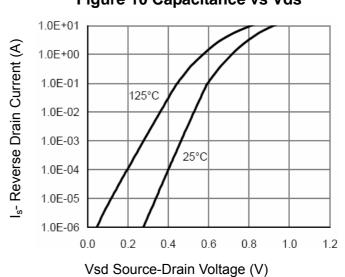
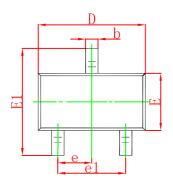
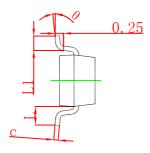


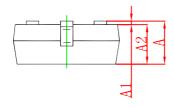
Figure 12 Source- Drain Diode Forward



SOT-23 Package Outline Dimensions

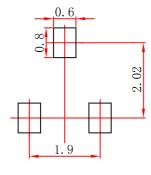






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



- Note:
 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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